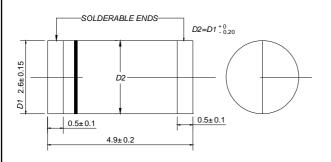


DLFR101 THRU DLFR107

SURFACE MOUNT RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V CURRENT: 1.0 A

DO - 213AB



Dimensions in millimeters

FEATURES

Plastic package has underwriters laboratories

flammability classification 94V-0

Glass passivated chip junction

For surface mount applications

High temperature metallurgically bonded construction

Cavity-free glass passivated junction

High temperature soldering guaranteed:450 /5 seconds at terminals.Complete device sub-mersible temperature

of 265 for 10 seconds in solder bath

MECHANICAL DATA

Case: JEDEC DO-213AB,molded plastic Terminals: Axial lead ,solderable per

MIL- STD-750, Method 2026

Polarity: Color band denotes cathode Weight: 0.0046 ounces, 0.116 grams

Mounting position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

MDD CatalogNumber		DL	DL	DL	DL	DL	DL	DL	UNITS			
		FR101	FR102	FR103	FR104	FR105	FR106	FR107	UNITS			
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V			
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V			
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V			
Maximum average forward rectified current	I _(AV) 1.0						А					
T _T =55	I _(AV)	1.0										
Peak forward surge current												
8.3ms single half-sine-wave	I _{FSM} 30							Α				
superimposed on rated load (JEDEC Method)												
Maximum instantaneous forward voltage @1.0A	V_{F}	1.3							V			
Maximum reverse current @T _A =25			5.0									
at rated DC blocking voltage @T _A =125	I _R 50						μA					
Maximum reverse recovery time (Note 1)	t _{rr}		15	0		250	50	00	ns			
Typical junction capacitance (Note 2)	C _j	15						pF				
Typical thermal resistance (Note 3)	$R_{\theta JA}$	75						/W				
Operating junction temperature range	T _j	- 55 +175										
Storage temperature range	T _{STG}	- 55 +175										

NOTE: 1. Measured with I_F=0.5A,I_R=1.0A,I_{rr}=0.25A

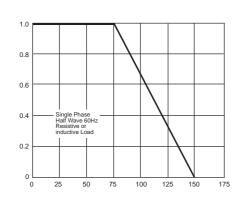
- 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- 3. Thermal resistance from junction to ambient, 0.24×0.24"(6.0×6.0mm) copper pads to each terminal.

MDD ELECTRONIC

RATINGS AND CHARACTERISTIC CURVES DLFR101 THRU DLFR107

FIG.1 - FORWARD CURRENT DERATING CURVE

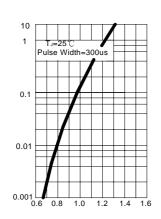
AVERAGE FORWARD RECTIFIED CURRENT, AMPERES



TERMINAL TEMPERATURE

FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

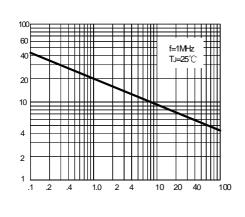
INSTANTANEOUS FORWARD CURRENT, AMPERES



INSTANTANEOUS FORWARD VOLTAGE(V)

FIG.5 - TYPICAL JUNCTION CAPACITANCE

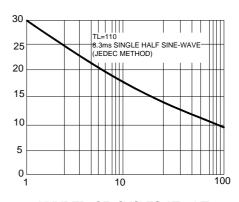




REVERSE VOLTAGE(V)

FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

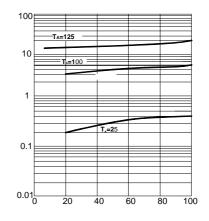
PEAK FORWARD SURGE CURRENT,AMPERES



NUMBER OF CYCLES AT 60HZ

FIG.4 - TYPICAL REVERSE CHARACTERISTICS

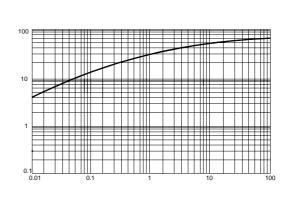
INSTANTANEOUS REVERSE LEAKAGE CURRENT(mA)



PERCENT OF RATED PEAK REVERSE VOLTAGE. (%)

FIG.6 - TYPICAL TRANSIENT THERMAL IMPEDANCE





T, PULSE DURATION,

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